NSN 5961-00-781-5218

No Fiig: A110a0

Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-00-781-5218 **Inclosure Material:** Glass **Overall Length:** 0.100 inches **Terminal Length:** 0.465 inches **Overall Diameter:** 0.045 inches **Mounting Method:** Terminal **Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 45.0 working peak reverse voltage, peak total value and 60.0 reverse voltage, instantaneous **Current Rating Per Characteristic:** 100.00 milliamperes forward current, total rms megahertz **Maximum Operating Tempurature Per Measurement Point:** 150.0 degrees celsius ambient air **Test Data Document:** 81349-mil-s-19500 specification (includes engineering type bulletins, brochures, etc., that reflect specification type data in specification format; excludes commercial catalogs, industry directories, and similar trade publications, reflecting general type data on certain environmental and performance requirements and test conditions that are shown as "typical", "average", "", etc.). **Terminal Type And Quantity:** 2 tab, solder lug **Specification Data:** 81349-mil-s-19500/230 government specification Shelf Life: N/a **Unit Of Measure: Demilitarization:**